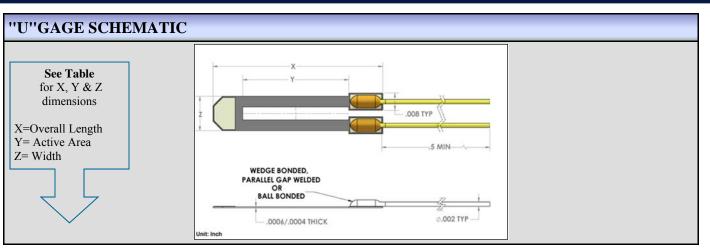
**DATA SHEET** 



"U" SHAPED GAGE							
Part Number	-	Lead		Resistance Ohms	Gage	TCGF	TCR
XY	Z	Attachment	Thickness	@ 78°F	Factor		
SS-018-011-3000PU	0.012	Ball Bond	0.0004	3000 ± 150	150 ± 10	-23%	42%
SS-028-008-400PU	0.016	Welded	0.0004	$400 \pm 40$	150 ± 10	-18%	24%
SS-037-022-500PU	0.016	Welded	0.0004	$540 \pm 50$	150 ± 10	-13%	17%
SS-047-025-350PU	0.016	Welded	0.0004	325 ± 40	100 ± 10	-10%	6%
SS-047-025-500PU	0.016	Welded	0.0004	540 ± 50	140 ± 10	-13%	16%
SS-047-025-1000PU	0.016	Welded	0.0004	1000 ± 100	160 ± 10	-20%	28%
SS-060-033-300PU	0.016	Welded	0.0004	$325 \pm 40$	100 ± 10	-10%	6%
SS-060-033-500PU	0.016	Welded	0.0004	540 ± 50	140 ± 10	-12%	14%
SS-060-033-2000PU	0.016	Welded	0.0004	2000 ± 100	155 ± 10	-18%	24%
SS-080-050-10000PU	0.013	Welded	0.0004	10000 ± 1000	175 ± 10	-23%	42%
SS-095-060-350PU	0.016	Welded	0.0004	350 ± 50	120 ± 10	-9%	5%



## **ORDERING INFORMATION**

## STANDARD SEMICONDUCTOR STRAIN GAGES

Micron semiconductor strain gages are made from "P" doped bulk silicon. This is a two terminal resistive device. The silicon is micro machined to shape thus eliminating molecular dislocation or cracks, thereby optimizing performance.

STANDARD GAGE SPECIFICATIONS			
Materials	Czochralski pulled boron doped silicon		
Leads	.002 dia. Gold x 0.5 in. long. Some gages have .0015 dia. Leads.		
Contact Pads	Gold nickel fused, vapor deposited gold or vapor deposited aluminum for Hi-Temp		
<b>Lead Attachments</b>	Parallel gap welded with epoxy reinforcement. Ball Bond or Wedge Bond		
Operating Strain	$\pm 2000~\mu$ inch/inch (3000 $\mu$ inch/inch max.)		
Linearity	Better than ±0.25% to 600 μ inch/inch		
	Better than $\pm 1.5\%$ to 1500 $\mu$ inch/inch		
Max. Operating Temperature	500°F		

Ordering Guidelines	Example					
$\begin{array}{c c} A \Rightarrow B \Rightarrow C \Rightarrow D \Rightarrow E \Rightarrow F \Rightarrow \leftarrow G \end{array}$	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$					
A. Model (SS)	SS-080-050-500P U S4 is a Semiconductor Strain gage with a total length of 080 and an active length of 050. The gage has a nominal resistance of 500 at 78 degrees F. The gage is further defined as Dopant P and Configured as a "U" Gage.					
B. Total Length						
C. Active Length						
<b>D.</b> Nominal Resistance at 78°F	S4 specifies a matched set of 4 gages.					
E. Dopant	Note: • S4 Matched set of 4 gages • S2 Matched set of 2 gages.					
F. U Gage, M Gage, or Leave Blank for Bar Gage*	S1 Single gage with data.					
G. Specifies Single, Matched or Bulk Gages	<ul> <li>S0 Bulk gage without data.</li> <li>*Specify Gage Type: "U", "M" or Leave Blank for Bar Gage.</li> <li>For Matched Sets of S5 up to sets of S16 Consult Factory</li> </ul>					

Standard Bridge Matching							
Temperature °F	<b>0</b> °	<b>78</b> °	278°				
Standard Matching	±0.6%	±0.4%	±0.4%	Percent of Base Resistance			

Note: Custom special matching gages (Mil-Spec.) or additional data points are also available.



